L Number	Hits	Search Text	DB	Time stamp
43	8154	(438/38,622,624,637,778,786,787,958,981,for		, 260349272CCL9:44
		·	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
50	19	imag\$3 near array and	USPĀT;	2003/02/21 10:45
		((438/38,622,624,637,778,786,787,958,981,fo		9, for.493).CCLS.)
			EPO; JPO; DERWENT;	
i			IBM TDB	
-	1	("6384461").PN.	USPĀT;	2003/02/20 11:42
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
-	0	6384461.URPN.	USPAT	2003/02/20 11:40
-	2	("5574292" "5616524").PN.	USPAT	2003/02/20 11:40
-	1219	first with ((silicon near (oxynitride oxy	USPAT;	2003/02/20 17:05
		near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.y N.sub.x"	US-PGPUB; EPO; JPO;	
		"siO.sub.yN.sub.x") (benzocyclobutene	DERWENT;	
		benzo near cyclo near butene benzo near	IBM TDB	
İ		cyclobutene benzocyclo near butene BCB)	_	
		(polyamide poly near amide)) and second		
_	366	<pre>with ((oxide dioxide di near oxide)) (first near2 (dielectric passivation</pre>	USPAT;	2003/02/21 09:05
	300	insulating insulation passivating) with	US-PGPUB;	2003/02/21 09.03
]	((silicon near (oxynitride oxy near	EPO; JPO;	
		nitride) "siO.sub.xN.sub.y" "si O.sub.x	DERWENT;	
		N.sub.y" "si O.sub.y N.sub.x"	IBM_TDB	
	İ	"siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)		i
		(polyamide poly near amide)) and second		
		near2 (dielectric passivation insulating		
		insulation passivating) with ((oxide		
		dioxide di near oxide))) and (first with ((silicon near (oxynitride oxy near		
		nitride) "siO.sub.xN.sub.y" "si O.sub.x		
		N.sub.y" "si O.sub.y N.sub.x"		
		"siO.sub.yN.sub.x") (benzocyclobutene		
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second	ĺ	
		with ((oxide dioxide di near oxide)))		
-	308	((first near2 (dielectric passivation	USPAT;	2003/02/20 17:06
		insulating insulation passivating) with	US-PGPUB;	
		((silicon near (oxynitride oxy near	EPO; JPO;	
		nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.y N.sub.x"	DERWENT; IBM TDB	
		"siO.sub.yN.sub.x") (benzocyclobutene	151155	
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)	17	
i		(polyamide poly near amide)) and second near2 (dielectric passivation insulating	:	, !
	j	insulation passivating) with ((oxide	İ	!
		dioxide di near oxide))) and (first with		
		((silicon near (oxynitride oxy near	,	
		nitride) "siO.sub.xN.sub.y" "si O.sub.x		
		N.sub.y" "si O.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene		
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)		
	1	(polyamide poly near amide)) and second		
	ĺ	with ((oxide dioxide di near oxide)))) and		
		(438/\$6 257/\$6)		

•				
	133	(((first near2 (dielectric passivation insulating insulation passivating) with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.x N.sub.y" "si O.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second near2 (dielectric passivation insulating insulation passivating) with ((oxide dioxide di near oxide))) and (first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.x"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/20 14:21
		"siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide)))) and (438/\$6 257/\$6)) and ("a" amorphous) near (silicon si)		
	93	mushroom near (shape shaped) near2 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/20 14:24
	2	(first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.x" "siO.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide))) and (mushroom near (shape shaped) near2 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/20 14:25
	2	((first near2 (dielectric passivation insulating insulation passivating) with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.x N.sub.y" "si O.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclobutene benzo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second near2 (dielectric passivation insulating insulation passivating) with ((oxide dioxide di near oxide))) and (first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.x N.sub.y" "siO.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide)))) and 257/458	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/20 14:27

-	70	(((first near2 (dielectric passivation	USPAT;	2003/02/20 14:29
		insulating insulation passivating) with	US-PGPUB;	
		((silicon near (oxynitride oxy near	EPO; JPO;	
		nitride) "siO.sub.xN.sub.y" "si O.sub.x	DERWENT;	
		N.sub.y" "si O.sub.y N.sub.x"	IBM TDB	
		"siO.sub.yN.sub.x") (benzocyclobutene	_	
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)		
ļ		(polyamide poly near amide)) and second	1	1
1	İ	near2 (dielectric passivation insulating	İ	İ
		insulation passivating) with ((oxide		
		dioxide di near oxide))) and (first with		
		((silicon near (oxynitride oxy near		
		nitride) "siO.sub.xN.sub.y" "si O.sub.x		
		N.sub.y" "si O.sub.y N.sub.x"		
		"siO.sub.yN.sub.x") (benzocyclobutene		
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)		
		(polyamide poly near amide)) and second		
		with ((oxide dioxide di near oxide)))) and		
		(438/\$6 257/\$6)) and (source drain "s/d")		
		near2 electrode		
-	2	(first with ((silicon near (oxynitride oxy	USPAT;	2003/02/20 14:47
		near nitride) "siO.sub.xN.sub.y" "si	US-PGPUB;	
		O.sub.x N.sub.y" "si O.sub.y N.sub.x"	EPO; JPO;	
		"siO.sub.yN.sub.x") (benzocyclobutene	DERWENT;	
		benzo near cyclo near butene benzo near	IBM TDB	
		cyclobutene benzocyclo near butene BCB)	_	
	ļ	(polyamide poly near amide)) and second		
		with ((oxide dioxide di near oxide))) and		
		lateral with leak\$3 with current		
_	3	(first with ((silicon near (oxynitride oxy	USPAT;	2003/02/20 14:49
		near nitride) "siO.sub.xN.sub.y" "si	US-PGPUB;	
		O.sub.x N.sub.y" "si O.sub.y N.sub.x"	EPO; JPO;	
		"siO.sub.yN.sub.x") (benzocyclobutene	DERWENT;	
		benzo near cyclo near butene benzo near	IBM TDB	
		cyclobutene benzocyclo near butene BCB)	1200_120	
		(polyamide poly near amide)) and second		
	1	with ((oxide dioxide di near oxide))) and		
		lateral\$2 with leak\$3 with current		
_	161	(first with ((silicon near (oxynitride oxy	USPAT;	2003/02/20 14:49
	101	near nitride) "siO.sub.xN.sub.y" "si	US-PGPUB;	2000, 02, 20 21119
		O.sub.x N.sub.y" "si O.sub.y N.sub.x"	EPO; JPO;	
		"siO.sub.yN.sub.x") (benzocyclobutene	DERWENT;	
		benzo near cyclo near butene benzo near	IBM TDB	
		cyclobutene benzocyclo near butene BCB)	***-**	1
		(polyamide poly near amide)) and second		
		with ((oxide dioxide di near oxide))) and	1	
	ļ	leak\$3 with current]	
_	308	((first near2 (dielectric passivation	USPAT;	2003/02/20 17:09
	300	insulating insulation passivating) with	US-PGPUB;	-000,02,20 1,.00
	[((silicon near (oxynitride oxy near	EPO; JPO;	
		nitride) "siO.sub.xN.sub.y" "si O.sub.x	DERWENT;	
		N.sub.y" "si O.sub.y N.sub.x"	IBM TDB	!
		"siO.sub.yN.sub.x") (benzocyclobutene	1	
	į l	benzo near cyclo near butene benzo near	1	
		cyclobutene benzocyclo near butene BCB)		
		(polyamide poly near amide)) and second		
1		near2 (dielectric passivation insulating		1
		insulation passivating) with ((oxide		
]	dioxide di near oxide))) and (first with		
		((silicon near (oxynitride oxy near		1
		nitride) "siO.sub.xN.sub.y" "si O.sub.x		
		N.sub.y" "si O.sub.y N.sub.x"		
		"siO.sub.yN.sub.x") (benzocyclobutene		
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)		
		(polyamide poly near amide)) and second		
		with ((oxide dioxide di near oxide)))) and		
		(438/\$6 257/\$6)		
L	L	1200/40 201/40/	L	L

-	521	first with ((silicon near (oxynitride oxy	USPAT;	2003/02/20 17:14
	ł	near nitride) "siO.sub.xN.sub.y" "si	US-PGPUB;	1
		O.sub.x N.sub.y" "si O.sub.y N.sub.x"	EPO; JPO;	
		"siO.sub.yN.sub.x") (benzocyclobutene	DERWENT;	
		benzo near cyclo near butene benzo near	IBM_TDB	
		cyclobutene benzocyclo near butene BCB)		
		(polyamide poly near amide)) and second		
		with ((oxide dioxide di near oxide)) and		
		(438/\$6 257/\$6) not (((first near2		
		(dielectric passivation insulating		
		insulation passivating) with ((silicon]
		near (oxynitride oxy near nitride)		1
		"siO.sub.xN.sub.y" "si O.sub.x N.sub.y"]
		"si O.sub.y N.sub.x" "siO.sub.yN.sub.x")		
		(benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo		
		near butene BCB) (polyamide poly near		
		amide)) and second near2 (dielectric		1
		passivation insulating insulation		!
		passivation insulating insulation passivating) with ((oxide dioxide di near		
		oxide))) and (first with ((silicon near		ŧ į
1		(oxynitride oxy near nitride)	i	
		"siO.sub.xN.sub.y" "si O.sub.x N.sub.y"		
		"si O.sub.y N.sub.x" "siO.sub.yN.sub.x")		
		(benzocyclobutene benzo near cyclo near		
		butene benzo near cyclobutene benzocyclo		
		near butene BCB) (polyamide poly near		
		amide)) and second with ((oxide dioxide di		
		near oxide)))) and (438/\$6 257/\$6))		
-	72	(dual two) near2 (dielectric passivation	USPAT;	2003/02/21 09:11
		insulating insulation passivating) with	US-PGPUB;	
		((silicon near (oxynitride oxy near	EPO; JPO;	
		nitride) "siO.sub.xN.sub.y" "si O.sub.x	DERWENT;	
		N.sub.y" "si O.sub.y N.sub.x"	IBM_TDB	
		"siO.sub.yN.sub.x") (benzocyclobutene	:	
		benzo near cyclo near butene benzo near		
		cyclobutene benzocyclo near butene BCB)		
		(polyamide poly near amide))	USPAT	2003/02/21 09:22
_	6	("4700457" "4985718" "4990463" "5006481" "5262354" "5312512").PN.	USFAI	2003/02/21 09.22
_	3	("5232970" "5288989" "5416233").PN.	USPAT	2003/02/21 09:23
_	9	("4577395" "4833094" "5026659"	USPAT	2003/02/21 09:23
		"5162248" "5270241" "5275974"		1
	1	"5292679" "5384152" "5604696").PN.		
_	1 2	full near fill near factor near image near	USPAT;	2003/02/21 09:46
		array	US-PGPUB;	
		-	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	full near fill near factor near image near	USPAT;	2003/02/21 09:48
		array	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		6133 6226 1	IBM_TDB	2002/02/21 22 42
-	10	fill near factor near imag\$3 near array	USPAT;	2003/02/21 09:49
	1		US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	8	fill near factor near image near array	USPAT;	2003/02/21 09:48
			US-PGPUB;	
			EPO; JPO;	
]		DERWENT;	
			IBM_TDB	
-	10	fill near2 factor near imag\$3 near array	USPĀT;	2003/02/21 09:51
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	<u> </u>		IBM_TDB	l

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-	12161	imag\$3 near array	USPAT;	2003/02/21 10:45
			US-PGPUB;	
]			EPO; JPO;	į
			DERWENT;	
			IBM_TDB	
-] 1	(imag\$3 near array) and upper near	USPAT;	2003/02/21 09:54
		electrode with (ito (tin indium) near2	US-PGPUB;	
		oxide) with pattern\$3	EPO; JPO;	!
1			DERWENT;	
			: IBM_TDB	
-	50	(imag\$3 near array) and electrode with	USPAT;	2003/02/21 09:54
		(ito (tin indium) near2 oxide) with	US-PGPUB;	į
		pattern\$3	EPO; JPO;	1
1			DERWENT;	
	10	// /	IBM_TDB	
-	4 9	((imag\$3 near array) and electrode with	USPAT;	2003/02/21 09:55
1		(ito (tin indium) near2 oxide) with	US-PGPUB;	
		pattern\$3) not ((imag\$3 near array) and	EPO; JPO;	
1		upper near electrode with (ito (tin	DERWENT;	
		<pre>indium) near2 oxide) with pattern\$3)</pre>	IBM TDB	